Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass or metal
Overall Length:
0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.085 inches and 0.105 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-7
Mounting Method:
Terminal
Features Provided:
Burn in
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
12.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
250.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector absolute
Capacitance Rating In Picofarads:
Between 9.0 and 15.0
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0